1.5A Flash LED Driver with I²C Compatible Interface

General Description

The RT8540 is a high efficiency synchronous Boost converter capable of delivering up to 1.5A maximum output current. It is an ideal power solution for up to three LEDs photoflash applications in all single-cell Lithium-ion/ polymer battery powered products.

The RT8540 maintains output current regulation by switching the internal high-side and low-side switch transistors. The transistor switches are pulse width modulated at a fixed frequency of 2MHz. The high switching frequency allows the use of a small inductor and output capacitor, making the RT8540 ideally suited for small battery powered applications. The RT8540 also includes STRB0, STRB1, Tx-MASK input to simplify torch and flash synchronization with the camera module. The default timer can be used to terminate a flash event after a user programmed delay or as a safety feature. The device automatically optimizes the LED flash current budget with the battery voltage condition as a feature.

The RT8540 not only operates as a regulated current source, but also as a voltage Boost regulator with the capability of down output voltage mode. The RT8540 contains over-voltage protection, over-current protection and a thermal management system to protect the device. The shutdown feature reduces shutdown current to less than 1 μ A. The RT8540 is available in the tiny WL-CSP-20B 1.82x2.22 (BSC) package to achieve best solution for PCB space and total BOM cost saving.

Features

- Input Voltage Range : 2.5V to 5.5V
- Three Flash LED Channel Output
- Operational Modes
 - Torch Mode and Flash Strobe
 - Voltage Regulation Converter with Down Output
 Voltage Mode
 - Shutdown Mode
- Up to 1.5A Regulated Output Current
- Up to 85% Efficiency with Small Magnetics at Current Regulation
- 2MHz Switching Frequency
- Dual Wire Camera Module Interface
- Tx-MASK Input to Inhibit Flash operation
- Shutdown Current < 1μA
- I²C Setting Torch Mode Current Level
- I²C Setting Flash Mode Current Level
- I²C Setting Safety Timer
- Over-Voltage (Open LED), Over-Current (Short Circuit), and Over-Temperature Protection
- Flash Current Optimization with VBAT
- LED Temperature Monitoring
- I²C Compatible Interface up to 3.4Mbits/s
- GPIO and Power Good Output
- Privacy Indicator LED Output
- Hardware Reset Input
- RoHS Compliant and Halogen Free

Simplified Application Circuit





Applications

- Single/Dual/Triple White LED Flash Supply for Cell Phones, Smart Phones, Tablet PC, Digital Cameras and other 3C productions
- Video Lighting for Digital Video Applications
- General LED Lighting Applications

Ordering Information

RT8540 🖵

—Package Type

WSC : WL-CSP-20B 1.82x2.22 (BSC)

Note :

Richtek products are :

- RoHS compliant and compatible with the current requirements of IPC/JEDEC J-STD-020.
- Suitable for use in SnPb or Pb-free soldering processes.

Marking Information

0PW

0P : Product Code

W : Date Code

Pin Configurations



WL-CSP-20B 1.82x2.22 (BSC)

Functional Pin Description

Pin No.	Pin Name	Pin Function
A1	INDLED	Constant Current Source Output. This pin provides a constant current source to drive low VF LEDs. Connect to LED anode.
A2	VOUT	Output of Boost Converter. Connect a $10\mu F$ or larger ceramic capacitor from VOUT to ground as close as possible to IC.
A3, A4	AGND	Analog Ground.
B1	SDA	Serial Interface Address/Data Input. This pin must not be left floating and must be terminated.
B2	SCL	Serial Interface Clock Input. This pin must not be left floating and must be terminated.
В3	NRESET	Master Hardware Reset Input. NRESET = LOW : The device is forced to shutdown mode. The I ² C control I/F and all internal control registers will be reset. NRESET = HIGH : The device operates normally.
B4	STRB0	LED1/2/3 Enable Control Input. This pin can be used to enable/disable the high power LEDs connected to the device. STRB0 = LOW : LED1, LED2 and LED3 current regulators are turned off. STRB0 = HIGH : LED2, LED2 and LED3 current regulators are active. The LED current level (video light or flash current) is defined according to the STRB1 logic level.
C1, C2	SW	Switch Node of Boost Converter. Connect an inductor between SW and VIN.
C3	Tx-MASK	LED Flash Inhibit Control Input. Pulling this pin high turns the LED from flash to video light operation, thereby reducing almost instantaneously the peak current loading from the battery.
C4	TS	NTC Resistor Connection. This pin can be used to monitor the LED temperature. Connect a $220k\Omega$ NTC resistor from the TS to ground. If this function is not used, the TS pin should be tied to VIN or left floating.
D1, D2	PGND	Power Ground. Connect PGND to AGND underneath IC. The exposed pace must be soldered to a large PCB and connected to GND for maximum power dissipation.
D3	STRB1	LED Current Level Selection Input. Pulling this input high disables the video light watchdog timer. STRB1 = LOW : flash mode is enabled. STRB1 = HIGH : video light mode is enabled.
D4	GPIO/PGOOD	GPIO Input or Power Good Indicator.
E1	LED2	Current Source of LED Channel 2.
E2	LED1	Current Source of LED Channel 1.
E3	LED3	Current Source of LED Channel 3.
E4	VIN	Power Input. Connect Battery to the input power supply voltage. Connect a 4.7μ F or larger ceramic capacitor from VIN to ground as close as possible to the IC.



Function Block Diagram



Operation

The RT8540 is a high efficiency synchronous Boost converter capable of delivering up to 1.5A maximum output current, and it maintains output current regulation by switching the internal high-side and low-side switch transistors. The transistor switches are pulse width modulated at a fixed frequency of 2MHz. The RT8540 also includes STRB0, STRB1, Tx-MASK input to simplify torch and flash synchronization with the camera module. The RT8540 is designed for one, two or three LEDs driving for torch and flash application, it provides an I²C software command or dedicated zero latency hardware signals to trigger the torch and flash operation. The OVP function prevents the RT8540 from damaging while open-LED or open-circuit condition is occurred.

RT8540

Absolute Maximum Ratings (Note 1)

Supply Voltage, VIN	0.3V to 6.5V
Boost Output Voltage, VOUT	0.3V to 6.5V
Switch Node Voltage, SW	0.3V to 6.5V
Current Source Voltage, LED1, LED2, LED3, INDLED	0.3V to 6.5V
Other Pins, STRB0, STRB1, SCL, SDA, Tx-MASK, TS, GPIO/PGOOD	0.3V to 6V
• Power Dissipation, $P_D @ T_A = 25^{\circ}C$	
WL-CSP-20B 1.82x2.22 (BSC)	2.72W
Package Thermal Resistance (Note 2)	
o	
WL-CSP-20B 1.82x2.22 (BSC), θ _{JA}	36.7°C/W
WL-CSP-20B 1.82x2.22 (BSC), θ _{JA}	150°C
WL-CSP-20B 1.82x2.22 (BSC), θ _{JA}	150°C 260°C
 WL-CSP-20B 1.82x2.22 (BSC), θ_{JA}	150°C 260°C
 WL-CSP-20B 1.82x2.22 (BSC), θ_{JA}	150°C 260°C –65°C to 150°C
 WL-CSP-20B 1.82x2.22 (BSC), θ_{JA} Junction Temperature	150°C 260°C –65°C to 150°C 2kV

Recommended Operating Conditions (Note 4)

Input Voltage, VIN	- 2.5V to 5.5V
Junction Temperature Range	 –40°C to 125°C
Ambient Temperature Range	- −40°C to 85°C

Electrical Characteristics

(V_{IN} = 3.7V, C_{IN} = 4.7 \mu F, C_{OUT} = 10 \mu F, T_A = 25 ^{\circ}C, unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit				
Power Supply										
Under-Voltage Lockout	VUVLO			2.3	2.4	V				
VIN Quiescent Current	IQ	I _{OUT} = 0mA, no switching (Voltage regulation mode)		590	700	μA				
VIN Shutdown Current	I _{SD}			1	5	μA				
Output										
Output Voltage Range		Current Regulation Mode	V _{IN}		5.5	V				
	Vout	Voltage Regulation Mode	3.825		5.7	v				
Internal Feedback Voltage Accuracy	V _{FB}	2.5V < V _{IN} < 4.8V, Boost mode, PWM voltage regulation	-2		2	%				
Output Over-Voltage	Maria	V_{OUT} Rising, $0000 \le OV$ [3:0] ≤ 0100	4.5	4.65	4.8					
Protection (OVP)	VOVP	V_{OUT} Rising, 0101 \leq OV [3:0] \leq 1111	5.8	6	6.2	V				
OVP Hysteresis	V _{OVP_HYS}	V _{OUT} Falling		150		mV				
Current Source of LED Cur	rent			-						
LED1/2 Current Acouracy	L	$0mA \leq I_{LED1/3} \leq 100mA$	-10		10	%				
LED1/3 Current Accuracy	LED1/3	$100 \text{mA} \le I_{\text{LED1/3}} \le 400 \text{mA} \qquad -7.5 \qquad$			7.5	70				
LED1/3 Current Matching	I _{MAT}		-10		10	%				



Parameter	,	Symbol	Test Conditions	Min	Тур	Мах	Unit
			$0mA \le I_{LED2} \le 250mA$	-10		10	
LED2 Current Accuracy		I _{LED2}	$250mA \le I_{LED2} \le 800mA$	-7.5		7.5	%
INDLED Current Accura	су	I _{IND}	$\begin{array}{l} 1.5V \leq (V_{IN}-V_{INDLED}) \leq 2.5V, \\ 2.6mA \leq I_{IND} \leq 15.8mA \end{array}$	-20		20	%
LED1/2/3 Current Temperature Coefficient					0.05		%/°C
INDLED Current Tempe Coefficient	rature				0.05		%/°C
LED1/2/3 Sense Voltage	Э	V _{SEN}	LED1/2/3 = Full-Scale Current		300		mV
LED1/2/3 Input Leakage	Current	I _{LED_LKG}	$V_{LED1/2/3} = 5V$		0.1	4	μΑ
INDLED Input Leakage	Current	IIND_LKG	V _{INDLED} = 0V		0.1	1	μΑ
LED1 Start-Up Current		I _{ST1}	LED Forward Voltage (V _{OUT} – V _{LED1}) < 1V	55			μA
LED2 Start-Up Current		I _{ST2}	LED Forward Voltage (V _{OUT} – V _{LED2}) < 1V	55			μA
LED3 Start-Up Current		I _{ST3}	LED Forward Voltage (V _{OUT} – V _{LED3}) < 1V	55			μA
Oscillator and Timer				-			-
Operating Frequency		Fosc	Flash Mode	1.8	2	2.2	MHz
Reset Pulse Width		t _{NRESET}		10			μS
Power Switch							
N-MOSFET R _{ON}		N _{RON}	V _{OUT} = 3.6V		75		mΩ
P-MOSFET R _{ON}		P _{RON}	V _{OUT} = 3.6V		95		mΩ
Leakage into SW		I _{LKG_SW}	$V_{OUT} = 0V, SW = 3.6V$		0.3	4	μΑ
Protection Function							
Current Limit			$V_{OUT} = 4.95 V$, ILIM = 0		1650		mA
		IOCP	V _{OUT} = 4.95V, ILIM = 1		2150	-	mA
Thermal Shutdown Thre	shold	T _{SD}		140	160		°C
Thermal Shutdown Hyst	eresis	T _{SD_HYS}			20		°C
Temperature Sense Cur	rent Source	I _{O_TS}	Thermistor Bias Current		23.8		μΑ
TS Resistance (Warning Temperature)]		LEDWARN bit = 1	39	44.5	50	kΩ
TS Resistance (Hot Terr	nperature)		LEDHOT bit = 1	12.5	14.5	16.5	kΩ
Logic Control							
SCL, SDA, GPIO/PGOOD, STRB0,	High-Level	VIH		1.2			v
STRB1, Tx-MASK, NRESET Input Voltage		VIL				0.4	
SDA Low-Level Output	Voltage	Vol_sda	$I_{OL} = 8mA$			0.3	V
GPIO Output Voltage	High-Level	V _{OH_GPIO}	DIR = 1, GPIOTYPE = 0, $I_{OH} = 8mA$	V _{IN} - 0.4			V
	Low-Level	Vol_gpio	DIR = 1, I _{OL} = 5mA			0.3	
STRB0, STRB1, NRESE Pull-Down Resistance	ET, Tx-MASK	R _{PD}	STRB0, STRB1, NRESET, Tx-MASK < 0.4V		400		kΩ

I²C Interface Timing Characteristics (1)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit			
	£	Standard mode			100				
SCL Clock Frequency	f _{SCL}	Fast mode			400	kHz			
Bus Free Time Between a	4	Standard mode	4.7						
STOP and START Condition	t _{BUF}	Fast mode	1.3			μs			
Hold Time (Repeated) START		Standard mode	4			μS			
Condition	t _{HD} , t _{STA}	Fast mode	600			ns			
LOW Period of the SCL Clock	+	Standard mode	4.7						
	t _{LOW}	Fast mode	1.3			μS			
HICH Dariad of the SCI. Clock	t	Standard mode	4			μS			
HIGH Period of the SCL Clock	tнigн	Fast mode	600			ns			
Setup Time for a Repeated		Standard mode	4.7			μS			
START Condition	t _{SU} , t _{STA}	Fast mode	600			ns			
Data Catur Tima		Standard mode	250						
Data Setup Time	t _{SU} , t _{DAT}	Fast mode	100			ns			
Deta Hald Time		Standard mode	0		3.45	μS			
Data Hold Time	t _{HD} , t _{DAT}	Fast mode	0		0.9				
Diaing Time of CCL Cignal	t _{RCL}	Standard mode	20 + 0.1C _B		1000				
Rising Time of SCL Signal		Fast mode	20 + 0.1C _B		300	- ns			
Rising Time of SCL Signal After a Repeated START		Standard mode	20 + 0.1C _B		1000				
Condition and After an Acknowledge BIT	^t RCL1	Fast mode	20 + 0.1C _B		300	ns			
Folling Time of SCI Signal	t	Standard mode	20 + 0.1C _B		300				
Falling Time of SCL Signal	t _{FCL}	Fast mode	20 + 0.1C _B		300	ns			
Rising Time of SDA Signal	*	Standard mode	20 + 0.1C _B		1000	20			
	t _{RDA}	Fast mode	20 + 0.1C _B		300	ns			
		Standard mode	20 + 0.1C _B		300				
Falling Time of SDA Signal	t _{FDA}	Fast mode	20 + 0.1C _B		300	ns			
Setup Time for STOP	. .	Standard mode	4			μS			
Condition	t _{SU} , t _{STO}	Fast mode	600			ns			
Capacitive Load for SDA and SCL	С _В				400	pF			

(1) Specified by design. Not tested in production.

- Note 1. Stresses beyond those listed "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions may affect device reliability.
- Note 2. θ_{JA} is measured at $T_A = 25^{\circ}C$ on a high effective thermal conductivity four-layer test board per JEDEC 51-7.
- Note 3. Devices are ESD sensitive. Handling precaution is recommended.
- Note 4. The device is not guaranteed to function outside its operating conditions.

Typical Application Circuit





Typical Operating Characteristics











LED1 + LED3 Current vs. Input Voltage



LED1 Current vs. LED1 Current Digital Code



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LED3 Current vs. LED3 Current Digital Code















Application Information

The RT8540 is a Boost converter that provides a current regulated output to drive high current white LEDs for camera flash applications. The IC adopts three channels to provide accurately regulated current flow through three separate white LEDs.

The RT8540 provides the ability to regulate the input voltage that is higher than the designed output voltage with its down-conversion mode. The RT8540 turns off its down-conversion mode automatically once the input voltage falls to approximately 200mV below the output voltage.

Soft-Start

The RT8540 employs a soft-start feature to limit the inrush current. The soft-start circuit prevents the excessive inrush current and input voltage droop. The soft-start clamps the input inrush current for a typical period of 400μ s.

Input UVLO

The input operating voltage range of the LED driver is from 2.5V to 5.5V. The RT8540 provides an under voltage lockout (UVLO) function to prevent it from unstable issue when startup. The UVLO threshold of input rising voltage is set at 2.3V typically with a hysteresis of 200mV.

Over Voltage Protection (Open-LED, Open-Circuit)

The RT8540 provides an internal over-voltage protection to limit its output voltage. The OVP function prevents the RT8540 from damaging while open-LED or open-circuit condition is occurred. The switching will be re-started again once the open circuit condition is removed, and then the IC will return to normal operation.

Over-Temperature Protection

The RT8540 provides an over-temperature protection to prevent the IC from overheating. When the junction temperature of the RT8540 rises above 160°C, the OTP function will be triggered and then the LED driver will be shutdown. The OTP of the RT8540 comes with a hysteresis of 20°C. Once the temperature is reduced below the over-temperature protection threshold by 20°C, the IC will enter normal operation again.

Inductor Selection

The RT8540 adopts fixed frequency PWM control architecture. For stable operation and the 2MHz high switching frequency, it is recommended to use a 2.2μ H inductor. Small size and high efficiency are the major concerns for portable device, so the inductor should have low core loss at 2MHz and low DCR for better efficiency.

Capacitor Selection

Input and output ceramic capacitors of 10μ F are recommended for RT8540 applications. For better voltage filtering, ceramic capacitors with low ESR are recommended. The best performance of the RT8540 can be achieved by using the capacitor of large capacitance. X5R and X7R types are suitable because of their wider voltage and temperature ranges.

Torch Mode and Flash Mode Operation

The RT8540 is designed for one, two or three LEDs driving for torch and flash application, it provides an I^2C software command or dedicated zero latency hardware signals to trigger the torch and flash operation.

LED Hardware Setup

In setting RT8540's hardware, the LED1, LED2 and LED3 pins must not be left floating to prevent the IC from overvoltage protection. For driving one or two LEDs with higher current, the LED1 to LED3 inputs should be connected together. Figure 1 shows the recommend LED setup for a single, dual or triple-LED application





Dual LED



Triple LED

Figure 1. White LED Hardware Setup Options

Triggering Torch and Flash

The RT8540 provides several options for driving the video light and flash. The IC operates in different modes according to different settings of the MODE_CTRL [1:0] bits for maximum system integration flexibility. The video light and flash can be triggered via hardware signals (STRB0, STRB1) or software I²C command. For torch lighting, the RT8540 provides a watchdog timer which must be refreshed within 13.0 seconds. This function can also be disabled as following description. MODE_CTRL [1:0] = 01

The STRB0, STRB1 inputs are disabled. No matter what situation of the STRB0, STRB1 inputs and the START_FLASH/TIMER (SFT) bit, the IC regulates the LED current in video light mode (DCLC bits).

MODE_CTRL [1:0] must be refreshed within less than 13.0 seconds (STRB1 = 0) to prevent the IC from shutdown due to video light safety timeout. Moreover, by pulling the STRB1 signal high, the video light watchdog timer can be disabled.

MODE_CTRL [1:0] = 10

The STRB0, STRB1 inputs are enabled. The RT8540 triggers the flash pulse by synchronization signals or by a software command (START_FLASH/TIMER (SFT) bit). According to the STRB0, STRB1 input, the LEDs can be enabled or disabled. Then, the flash safety timer will be activated and the video light watchdog timer will be disabled.

Level-Sensitive Flash Trigger (STT = 0)

In this mode, the RT8540 drives the high-power LEDs by flash-current level and the safety timer (STIM) is activated. The STIM [2:0] register determines the maximum duration of the flash pulse.

A rising edge triggers the safety timer and it can be stopped by a negative logic on the synchronization source (STRB0, STRB1 = 0) or by a timeout event (TO bit).



Figure 2. Hardware Synchronized Video Light and Flash Strobe

Rising-Edge Flash Trigger (STT = 1)

In this mode, the RT8540 drives the high power LEDs by flash-current level and the safety timer (STIM) is activated. The STIM [2:0] register determines the maximum duration

of the flash pulse. The RT8540 triggers the flash strobe by adopting a rising edge on the synchronization source (STRB0, STRB1 = 0) or a positive transition on the START-FLASH/TIMER (SFT) bit.



Figure 3. Edge Sensitive Timer (Single Trigger Event)

Down Mode

Normally, a Boost converter regulates output voltages which are higher than the input voltage. For better conversion when input voltages are higher than output voltages, a down mode is implemented. In the voltageregulation mode, when the input voltage reaches or exceeds the output voltage, the converter enters down mode. In this mode, the behavior of internal P-MOSFET is changed and increases the power losses in the converter which should be taken into account for thermal design. As soon as the input voltage falls to approximately 200mV below the output voltage, the down mode is automatically turned off.

Voltage Mode

In this mode, the RT8540 operates as a constant output voltage Boost regulator. By setting the mode control bit MODE_CTRL [1:0] = 11, the IC enters voltage mode operation. A constant output voltage can be regulated by the RT8540 according to the OV [3:0] bit settings (between 3.825V and 5.7V in 125mV steps). The LED current sinks LED1 to LED2 will be turned off in voltage mode.

The RT8540 provides an integrated software control bit (ENVM bit) to force the converter to enter voltage mode operation.

Internal Register Settings Mode_Ctrl [1:0]	ENVM bit	Operating Modes
11	0	LEDs are turned off and the converter
00	1	operates in voltage regulation mode (VM);
11	1	the output voltage is set via register OV [3:0].

Indicator

The RT8540 provides privacy indicator that can be used to indicate when a person is being photographed or filmed. The privacy indicator can be activated by adopting INDC [3:0] bits, ranging from 2.6mA to 15.8mA in 7 programmable current steps or by using the white LEDs with pulse width modulation.

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RT8540 Register Summary

Address: 0110011x

Address	Name	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
	Control10	RESET	FREE	D	CLC13 [2:0)]	DCLC2 [2:0]		
0x00	Reset Value	0	0	0	0	1	0	1	0
	Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
	Control1	MODE_C	TRL [1:0]			FC2 [5	5:0]		
0x01	Reset Value	0	0	0	1	0	0	0	0
	Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
	Control2	MODE_C	TRL [1:0]	ENVM			FC13 [4:0]		
0x02	Reset Value	0	0	0	0	1	0	0	0
	Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
	Control3		STIM [2:0]	HPLF	SELSTIM (W) TO (R)	STT	SFT	Tx-MASK
0x03	Reset Value	1	1	0	0	0	0	0	0
	Read/Write	R/W	R/W	R/W	R	R	R/W	R/W	R/W
	Control4	PG	HOTE	DIE [1:0]	ILIM	INC [3:0]			
0x04	Reset Value	0	0	0	0	0	0	0	0
	Read/Write	R/W	R	R	R/W	R/W	R/W	R/W	R/W
0.405	Control5	NA	ENPSM	DIR(W) STSTRB1 (R)	GPIO	GPIOTYPE	ENLED3	ENLED2	ENLED1
0x05	Reset Value	0	1	1	0	1	0	1	0
	Read/Write	R	R/W	R/W	R/W	R/W	R/W	R/W	R/W
	Control6	ENTS	LEDHOT	LEDWARN	LEDHDR		OV [3	3:0]	
0x06	Reset Value	0	0	0	0	1	0	0	1
	Read/Write	R/W	R/W	R	R	W	W	W	W
	Control7	ENBATM ON	BA	ATDROOP [2	:0]	FREE	F	REVID [2:0]	
0x07	Reset Value	0	1	0	0	0	1	1	0
	Read/Write	R/W	R/W	R/W	R/W	R/W	R	R	R



Address	Name	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0	
	Control10	RESET	FREE	Γ	DCLC13 [2:0)]		DCLC2 [2:0]	
0x00	Reset Value	0	0	0	0	1	0	1	0	
	Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	
RESET DCLC13 [2:0] DCLC2 [2:0]			operation. values are		ternal registe	ers.				
		Video Light Current Control bits (LED1/3). 000 : 0mA 001 : 25mA 010 : 50mA 011 : 75mA 100 : 100mA 101 : 125mA 110 : 150mA 111 : 175mA								
		Video Ligh 000 : 0mA 001 : 25m/ 010 : 50m/ 011 : 75m/ 100 : 100n 101 : 125n 110 : 150n 111 : 175n	A A 1A 1A 1A	ontrol bits (l	LED2).					
Address	Name	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0	
	Control1	MODE_C	TRL [1:0]			FC2	[5:0]			
0x01	Reset Value	0	0	0	1	0	0	0	0	
	Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	
MODE	_CTRL [1:0]	Register Reset bit. 00 : Device in shutdown mode. 01 : Device operations in video light mode. 10 : Device operation in Flash mode. 11 : Device operation as constant voltage source. To avoid device shutdown by video light safety timeout, MODE_CTRL [1 : 0] bits need to be refreshed within less than 13.0s. Writing to REGISTER1 [7 : 6] automatically updates REGISTER2 [7 : 6].								
FC2 [5:0]		Flash Curr 000000 : 0 000001 : 2 000010 : 5 000011 : 7 000100 : 1 000101 : 1 000110 : 1 000111 : 1 000111 : 1 000111 : 1	5mA 0mA 5mA 00mA 25mA 50mA 75mA 75mA	bits (LED2)						



FC	2 [5:0]	001001 : 2 001010 : 2 001011 : 2 001011 : 2 001100 : 3 001101 : 3 001110 : 3 001111 : 3 010000 : 4 010001 : 4 010001 : 4 010011 : 4 010010 : 5 010101 : 5 010101 : 5 010101 : 5 010101 : 5 010101 : 6 011001 : 6 011001 : 6 011001 : 6 011011 : 6 011011 : 7 011101 : 7 011110 : 7 011111 : 7 1000001	50mA 75mA 00mA 25mA 50mA 75mA 00mA 25mA 50mA 75mA 00mA 25mA 50mA 75mA 00mA 25mA 50mA 75mA 50mA)mA					
Address	Name	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
	Control2	MODE_C	TRL [1:0]	ENVM			FC13 [4:0]		
0x02	Reset Value	0	0	0	0	1	0	0	0
	Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
MODE_CTRL [1:0] Register Reset bit. 00 : Device in shutdown mode. 01 : Device operations in video light mode. 10 : Device operation in Flash mode. 11 : Device operation as constant voltage source. To avoid device shutdown by video light safety timeout, MODE_CTRL [1 : 0] bits be refreshed within less than 13.0s. Writing to REGISTER2 [6 : 5] automatically updates REGISTER1 [6 : 5] .						s need to			
E	NVM	0 : Normal 1 : Forces	the device i	nto a consta	ant voltage s comatically u		eflect the lo	gic stats of	the ENVM
FC	13 [4:0]	Flash Curr 00000 : 0m 00001 : 25 00010 : 50 00011 : 75 00100 : 10 00101 : 12 00110 : 15 00111 : 17 00111 : 17 01000 : 20	mA mA 0mA 5mA 0mA 5mA 5mA	bits (LED1/	3).				



FC	13 [4:0]	01001 : 22 01010 : 25 01011 : 27 01100 : 30 01101 : 32 01110 : 35 01111 : 37 1000011	50mA 75mA 90mA 25mA 50mA	A					
Address	Name	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
000	Control3		STIM [2:0]		HPLF	SELSTIM (W) TO (R)	STT	SFT	Tx-MASK
0x03	Reset Value	1	1	0	0	0	0	0	0
	Read/Write	R/W	R/W	R/W	R	R	R/W	R/W	R/W
		Safety Tim	ner bits.						
		STIN	/ [2:0]	RANG	GE 0	RANGE 1			
		0	00	68.2	ms	5.3ms			
			01	102.2		10.7ms			
		010		136.3		16.0ms			
ST	STIM [2:0]		11	170.4	lms	21.3ms			
		STIM [2:0] RANG			GE 0	RANGE 1			
		1	100		īms	26.6ms			
		1	101		Bms	32.0ms			
		110		579.3	Bms	37.3ms			
		1	11	852r	852ms 71.5ms				
F	IPFL	0 : Proper	er LED Failu LED operation Den or OCP.	tion.					
SE	LSTIM	0 : Safety	timer Selectio timer range timer range	0.	/rite Only).				
	то	0:Notime	Flag (Read e-out event ut event occ	occurred.	e-out flag is	s reset at re-s	tart of the	safety timer	
	STT	0 : LED sa 1 : LED sa	her Trigger h fety timer is fety timer is only valid fo	s level sens s rising edg	e sensitive				
	SFT	In write m 0 : No cha 1 : High-po In read mo 0 : High-po	nge is the h ower LED c	high-power l urrent ramp indicates th are idle.	LED currer os to the fla ne high-pov	e sequence. ht. ash current lev ver LED statu			



Tx-	MASK	In write mc 0 : Flash b 1 : LED cu In read mo Tx-MASK 1 0 : No flash	lanking disa rrent is redu de, this flag	enables/d abled. uced to vic indicates after read event occu	isables the fla deo light level whether or no lout of the flag irred.	when Tx-M ot the flash r	ASK input i	s high.		
Address	Name	Bit7 Bit6 Bit5 Bit4 Bit3 Bit2 Bi						Bit1	Bit0	
	Control4	PG	HOTD	IE [1:0]	ILIM		INC	[3:0]		
0x04	Reset Value	0	0	0	0	0	0	0	0	
	Read/Write	R/W	R	R	R/W	R/W	R/W	R/W	R/W	
Power Good bit. In write mode, this bit selects the functionality of the GPIO/PG output. 0 : PG signal is routed to the GPIO port. 1 : GPIO PORT VALUE bit is routed to the GPIO port. In read mode, this bit indicates the output voltage conditions. 0 : The converter is not operating within the voltage regulation limits. 1 : The output voltage is within its nominal value.										
нот	DIE [1:0]	Instantaneous Die Temperature bits. $00: T_J < +55^{\circ}C.$ $01: +55^{\circ}C < T_J < +70^{\circ}C.$ $10: T_J > +70^{\circ}C.$ 11: Thermal shutdown tripped. Indicator flag reset after readout.								
		Inductor Valley Current Limit bit. The ILIM bit can only be set before the device enters operation (i. e. initial shutdown state).								
	ILIM	Valley C	urrent Limit	Setting	ILIM Bi	t Setting				
			1650mA		Low					
			2150mA		H	High				
			ight Control NDC [3:0]	bits.	Privacy Indica		Channel			
		!	0000		Privacy indica					
			0001		INDLED curr					
			0010		INDLED curr					
INC	DC [3:0]		0011		INDLED curr					
			0100		Privacy indica					
			0101		INDLED current = 5.2mA					
			0110		INDLED curr	ent = 10.4m	A			
			0111		INDLED curr	ent = 15.8m	A			



		· · · · · ·		r						1	
		INDC [3:0]			Privacy Indicator LED1/3 Channel (1)						
		0000			5% PWM dimming rato						
		0001				11%	PWM dimmi	ng rato			
		0010				17%	PWM dimmi	ng rato			
INE	DC [3:0]	0011				23%	PWM dimmi	ng rato			
		0100			30% PWM dimming rato						
		0101			36% PWM dimming rato						
		0110				48%	PWM dimmi	ng rato			
			0111			67%	PWM dimmi	ng rato			
Address	Name	Bit7	Bit6	Bit5		Bit4	Bit3	Bit2	В	it1	Bit0
	Control5	NA	ENPSM	DIR(W) STSTRB1		GPIO	GPIOTYPE	ENLED3	ENL	.ED2	ENLED1
0x05	Reset Value	0	1	1		0	1	0	1		0
	Read/Write	R	R/W	R/W		R/W	R/W	R/W	R	/W	R/W
ENPSM		Enable/Disable Power-Save Mode bit. 0 : Power-save mode disabled. 1 : Power-save mode enabled.									
ST	STRB1	STRB1 Input Status bit (Read Only). This bit indicates the logic state on the STRB1 state.									
DIR		GPIS Direction bit. 0 : GPIO configured as input. 1 : GPIO configured as output.									
GPIO		GPIO Port Value. This bit contains the GPIO port value.									
GPIOTYPE		GPIO Port Type. 0 : GPIO is configured as push-pull output. 1 : GPIO is configured as open-drain output.									
ENLED3		Enable/Disable High-Current LED3 bit. 0 : LED3 input is disabled. 1 : LED3 input is enabled.									
ENLED2		Enable/Disable High-Current LED2 bit. 0 : LED2 input is disabled. 1 : LED2 input is enabled.									
ENLED1		Enable/Disable High-Current LED1 bit. 0 : LED1 input is disabled. 1 : LED1 input is enabled.									

Address	Name	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0			
	Control6	ENTS	LEDHOT	LEDWARN	LEDHDR		OV	[3:0]				
0x06	Reset Value	0	0	0	0	1	0	0	1			
	Read/Write	R/W	R/W	R	R	W	W	W	W			
ENTS		Enable/Disable LED Temperature Monitoring. 0 : LED temperature monitoring disabled. 1 : LED temperature monitoring enabled.										
LEDHOT		LED Excessive Temperature Flag. This bit can be reset by writing a logic level zero. 0 : TS input voltage > 0.345V. 1 : TS input voltage < 0.345V.										
LEDWARN		LED Temperature Warning Flag (Read Only). This flag is reset after readout. 0 : TS input voltage > 1.05V. 1 : TS input voltage < 1.05V.										
LEDHDR		LED High-Current Regulator Headroom Voltage Monitoring bit. This bit returns the headroom voltage status of the LED high-current regulators. This value is being updated at the end of a flash strobe, prior to the LED current ramp-down phase. 0 : Low headroom voltage. 1 : Sufficient headroom voltage.										
		In write mode, these bits are used to set the target output voltage (refer to voltage regulation mode). In applications requiring dynamic voltage control, care should be taken to set the new target code after voltage mode operation has been enabled (MODE_CTRL [1:0] = 11 and/or ENVM bit = 1).										
			000		3.825V							
			001		3.950V							
		0	010		4.075V							
			011		4.200V							
		0	100		4.325V							
0	V [3:0]	0	101		4.450V							
		0	110		4.575V							
		0	111		4.700V							
		1	000		4.825V							
		1	001		4.950V							
		1	010		5.075V							
		1	011		5.200V							
		1	100		5.325V							
		1	101		5.450V							
			110		5.575V							
		1	111		5.700V							



Address	Name	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0			
	Control7	ENBATMON	BA	BATDROOP [2:0]			REVID [2:0]					
0x07	Reset Value	0	1	0	0	0	1	1	0			
	Read/Write	R/W	R/W	R/W	R/W	R/W	R	R	R			
ENBATMON		Enable/Disable Battery Voltage Droop Monitoring Bit. 0 : Battery voltage droop monitoring disable. 1 : Battery voltage droop monitoring enable.										
BATDROOP [2:0]		Battery Voltage 000 : 50mV. 001 : 75mV. 010 : 100mV. 011 : 125mV. 100 : 150mV. 101 : 175mV. 110 : 200mV. 111 : 225mV	e Droop.									
REVID [2:0]		Silicon Revision ID.										

Thermal Considerations

For continuous operation, do not exceed absolute maximum junction temperature. The maximum power dissipation depends on the thermal resistance of the IC package, PCB layout, rate of surrounding airflow, and difference between junction and ambient temperature. The maximum power dissipation can be calculated by the following formula :

$\mathsf{P}_{\mathsf{D}(\mathsf{MAX})} = (\mathsf{T}_{\mathsf{J}(\mathsf{MAX})} - \mathsf{T}_{\mathsf{A}}) / \theta_{\mathsf{J}\mathsf{A}}$

where $T_{J(MAX)}$ is the maximum junction temperature, T_A is the ambient temperature, and θ_{JA} is the junction to ambient thermal resistance.

For recommended operating condition specifications, the maximum junction temperature is 125°C. The junction to ambient thermal resistance, θ_{JA} , is layout dependent. For WL-CSP-20B 1.82x2.22 (BSC) package, the thermal resistance, θ_{JA} , is 36.7°C/W on a standard JEDEC 51-7 four-layer thermal test board. The maximum power dissipation at $T_A = 25$ °C can be calculated by the following formula :

$$\label{eq:P_D(MAX)} \begin{split} P_{D(MAX)} &= (125^{\circ}C - 25^{\circ}C) \; / \; (36.7^{\circ}C/W) = 2.72W \; \text{for} \\ WL\text{-}CSP\text{-}20B \; 1.82x2.22 \; (BSC) \; \text{package} \end{split}$$

The maximum power dissipation depends on the operating ambient temperature for fixed $T_{J(MAX)}$ and thermal resistance, θ_{JA} . The derating curve in Figure 4 allows the designer to see the effect of rising ambient temperature on the maximum power dissipation.



Figure 4. Derating Curve of Maximum Power Dissipation

Layout Consideration

For the best performance of the RT8540, following PCB layout guidelines should be strictly followed.

- The AGND and PGND of the IC should be connected to the ground plane of the PCB.
- The output bypass capacitor should be placed as close to the IC as possible.
- The trace lengths from the IC to the inductor, input capacitor and the output capacitor must be kept as short, direct and wide as possible.
- ➤ C_{IN} and C_{OUT} of the RT8540 should be placed as close as possible and connected to PGND of the IC.
- It is recommended to add additional PCB exposed pad area for the flash LEDs for maximized heat-sinking ability. This is necessary for high current application and long flash duration application.







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Outline Dimension



Symbol	Dimensions I	n Millimeters	Dimensions In Inches			
Symbol	Min.	Max.	Min.	Max.		
A	0.500	0.600	0.020	0.024		
A1	0.200	0.260	0.008	0.010		
b	0.290	0.350	0.011	0.014		
D	D 2.170		0.085	0.089		
D1	1.6	600	0.063			
E	1.770	1.870	0.070	0.074		
E1	1.2	200	0.047			
е	0.4	00	0.016			

20B WL-CSP 1.82x2.22 Package (BSC)

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